

DOCKET NO. : LIN 12-37

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Wen Lin, et al.

For: SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE  
MATCHING LAYER AND A METHOD OF MANUFACTURE  
THEREFOR

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

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Elizabeth Schumach  
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Sir:

PRELIMINARY AMENDMENT

Before examination of the above-identified application, please amend it as follows:

IN THE SPECIFICATION

Please amend the specification by inserting before the first line the sentence:

--This Application is a Divisional of prior Application Serial No. 10/003,873 filed on  
October 24, 2001, currently pending, to Wen Lin, et al.. The above-listed Application is commonly  
assigned with the present invention and is incorporated herein by reference as if reproduced herein  
in its entirety under Rule 1.53(b).--